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"Phase Transformation in Materials"

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Equilibrium in Heterogeneous Systems





1455°C

Solidus

III

Ni

Liquidus

Т

%

ΤL



Summary I : Binary phase diagrams

1) Simple Phase Diagrams

Both are ideal soln. \rightarrow 1) Variation of temp.: $G^L > G^s$ 2) Decrease of curvature of G curve (\because decrease of $-T\Delta S_{mix}$ effect)

2) Systems with miscibility gap $\Delta H_{mix}^{L} = 0$ $\Delta H_{mix}^{S} > 0$ 1)Variation of temp.: **G**^L > **G**^s 2)Decrease of curvature of G curve + Shape change of G curve by H

- **4) Simple Eutectic Systems** $\Delta H_{mix}^{L} = 0 \quad \Delta H_{mix}^{S} >> 0$ \rightarrow miscibility gap extends to the melting temperature.
- **3) Ordered Alloys** $\Delta H_{mix}^{L} = 0$ $\Delta H_{mix}^{S} < 0$ $\Delta H_{mix} < 0 \rightarrow A$ atoms and B atoms like each other. \rightarrow Ordered alloy at low T

 $\Delta H_{mix} \ll 0 \rightarrow$ The ordered state can extend to the melting temperature.

5) Phase diagrams containing intermediate phases

Stable composition **†** Minimum G with stoichiometric composition

The Gibbs Phase Rule For Constant Pressure, P + F = C + 1



single phase

= 2 - 1 + 1

can vary T and

composition

F = C - P + 1

= 2



Q: heat absorbed (enthalpy) when 1 mole of β dissolves in A rich α as a dilute solution.

* Limiting forms of eutectic phase diagram

The solubility of one metal in another may be so low.



Fig. 54. Impossible form of a binary eutectic phase diagram.

a) 평형에 미치는 공공의 영향

Equilibrium concentration X_v^e will be that which gives the minimum free energy.



The G curves so far have been based on the molar Gs of infinitely large amounts of material of a perfect single crystal. Surfaces, GBs and interphase interfaces have been ignored.

1.6 Influence of Interfaces on Equilibrium - b) 평형에 미치는 계면의 영향

$$\Delta G = \Delta P \cdot V \implies \Delta G = \frac{2\gamma V_m}{r}$$

Extra pressure ΔP due to curvature of the α/β





dG =
$$\Delta G_{\gamma} dn = \gamma dA$$
 $\Delta G_{\gamma} = \gamma dA/dn$
Since n=4 $\pi r^3/3V_m$ and A = 4 πr^2 $\Delta G = \frac{2\gamma V_m}{r}$



Fig. 1.38 The effect of interfacial E on the solubility of small particle



Fig. 1.39 Transfer of dn mol of $\boldsymbol{\beta}$ from large to a small particle.

Gibbs-Thomson effect (capillarity effect):

Free energy increase due to interfacial energy

Quite large solubility differences can arise for particles in the range r=1-100 nm. However, for particles visible in the light microscope (r>1um) capillarity effects are very small.



Fig. 1.38 The effect of interfacial energy on the solubility of small particles.

$$X_{B}^{e} = A \exp\left\{-\frac{Q}{RT}\right\}$$
$$X_{B}^{e} = \exp\left(-\frac{\Delta G_{B} + \Omega}{RT}\right)$$
$$X_{B}^{r=\infty} = \exp\left(-\frac{\Delta G_{B} + \Omega}{RT}\right)$$
$$X_{B}^{r=r} = \exp\left(-\frac{\Delta G_{B} + \Omega}{RT}\right)$$
$$= X_{B}^{r=\infty} \exp\left(-\frac{\Delta G_{B} + \Omega - 2\gamma V_{m}/r}{RT}\right)$$

For small values of the exponent,

$$\frac{X_B^{r=r}}{X_B^{r=\infty}} = \exp(\frac{2\gamma V_m}{RTr}) \approx 1 + \frac{2\gamma V_m}{RTr}$$

Ex) $\gamma = 200 \text{mJ/m}^2$, $V_m = 10^{-5} \text{ m}^3$, T = 500 K $\frac{X_r}{X_{\infty}} = 1 + \frac{1}{r(nm)}$ For r=10 nm, solubility~10% increase

1.8 Additional Thermodynamic Relationships for Binary Solutions

Gibbs-Duhem equation: Calculate the change in (dµ) that results from a change in (dX)

Additional Thermodynamic Relationships for Binary Solutions

The Gibbs-Duhem Equation 합금조성의 미소변화 (dX)로 인한 화학퍼텐셜의 미소변화(dµ)를 계산 be able to calculate the change in chemical potential (dµ) that result from a change in alloy composition (dX).

① For a regular solution,

(2)

$$G = X_{A}G_{A} + X_{B}G_{B} + \Omega X_{A}X_{B} + RT(X_{A}\ln X_{A} + X_{B}\ln X_{B})$$

$$\frac{d^{2}G}{dX^{2}} = \frac{RT}{X_{A}X_{B}} - 2\Omega$$
For a ideal solution, $\Omega = 0$, $\frac{d^{2}G}{dX^{2}} = \frac{RT}{X_{A}X_{B}}$

$$\textcircled{O} \quad \begin{array}{l} \text{Different form} \\ \text{Eq. 1.65} \end{array} \quad \mu_{B} = G_{B} + RT\ln_{B} = G_{B} + RT\ln\gamma_{B}X_{B}$$

$$\xrightarrow{V_{B} = a_{B}/X_{B}} \xrightarrow{V_{B} = a_{B}/X_{B}} \xrightarrow{U_{B} = a_{B}/X_{B}} \xrightarrow{U_{B}/X_{B}} \xrightarrow{U_$$

13

$$\frac{d\mu_B}{dX_B} = \frac{RT}{X_B} \left\{ 1 + \frac{X_B}{\gamma_B} \frac{d\gamma_B}{dX_B} \right\} = \frac{RT}{X_B} \left\{ 1 + \frac{d\ln\gamma_B}{d\ln X_B} \right\}$$
 Eq. 1.69

a similar relationship can be derived for $d\mu_A/dX_B$

$$\begin{bmatrix} -X_A d\mu_A = X_B d\mu_B = RT \left\{ 1 + \frac{d\ln\gamma_A}{d\ln X_A} \right\} dX_B = RT \left\{ 1 + \frac{d\ln\gamma_B}{d\ln X_B} \right\} dX_B \\ = RT \left\{ 1 + \frac{d\ln\gamma_B}{d\ln X_B} \right\} dX_B \\ \text{Eq. 1.70} \\ \text{Eq. 1.65} \end{bmatrix}$$

The Gibbs-Duhem Equation

$$X_A X_B \frac{d^2 G}{dX^2} = RT \left\{ 1 + \frac{d \ln \gamma_A}{d \ln X_A} \right\} = RT \left\{ 1 + \frac{d \ln \gamma_B}{d \ln X_B} \right\}$$

be able to calculate the change in chemical potential $(d\mu)$ that result from a change in alloy composition (dX).

14

Total Free Energy Decrease per Mole of Nuclei ΔG_{n} : 변태를 위한 전체 구동력/핵생성을 위한 구동력은 아님 **Driving Force for Precipitate Nucleation** $\alpha \rightarrow \alpha + \beta$ $\Delta \mathbf{G}_{\mathbf{V}}$ $\Delta G_1 = \mu_A^{\alpha} X_A^{\beta} + \mu_B^{\alpha} X_B^{\beta}$ α : Decrease of total free E of system by removing a small amount of material **-** β $\alpha + \beta$ with the nucleus composition (X_B^{β}) (P point) T_2 $\Delta G_2 = \mu_A^\beta X_A^\beta + \mu_B^\beta X_B^\beta$: Increase of total free E of system (a) A X_{e} X_0 X^{β} by forming β phase with composition X_{R}^{β} $X_{\rm B} \longrightarrow$ В (Q point) $@T_2$ $\Delta G_n = \Delta G_2 - \Delta G_1$ (length PQ) μ_{B}^{α} G G^{α} $\Delta G_{V} = \frac{\Delta G_{n}}{V}$ per unit volume of β : driving force for β precipitation ΔG_n For dilute solutions, IG^β μβ ΔG_0 μβ $\Delta G_{V} \propto \Delta X$ where $\Delta X = X_{0} - X_{e}$ μ^a_A $\Delta G_{V} \propto \Delta X \propto (\Delta T)$ 15 \propto undercooling below T_a (b) 0 $X_{\rm R}$ – 1

Summary II: Binary phase diagrams

- Gibbs Phase Rule Gibbs' Phase Rule allows us to construct phase diagram to represent and interpret phase equilibria in heterogeneous geologic systems.
- Effect of Temperature on Solid Solubility

$$X_B^e = A \exp\left\{-\frac{Q}{RT}\right\}$$
 a) $T \uparrow \implies X_B^e \uparrow$ **b)** X_B^e can never be equal to

Equilibrium Vacancy Concentration



zero.

Influence of Interfaces on Equilibrium

$$\Delta G = \frac{2\gamma V_m}{r}$$
 Gibbs-Thomson effect

• Gibbs-Duhem Equation: Be able to calculate the change in

chemical potential that result from a change in alloy composition.

$$X_A X_B \frac{d^2 G}{dX^2} = RT \left\{ 1 + \frac{d \ln \gamma_A}{d \ln X_A} \right\} = RT \left\{ 1 + \frac{d \ln \gamma_B}{d \ln X_B} \right\}$$

합금조성의 미소변화 (dX)로 인한 화학퍼텐셜의 미소변화**(d**μ) 를 계산

What are ternary phase diagram?

Diagrams that represent the equilibrium between the various phases that are formed between three components, as a function of temperature.

Normally, pressure is not a viable variable in ternary phase diagram construction, and is therefore held constant at 1 atm.

Gibbs Phase Rule for 3-component Systems

F = C + 2 - P

For isobaric systems:

F = C + 1 - P

For C = 3, the maximum number of phases will co-exist when F = 0

P = 4 when C = 3 and F = 0

Components are "independent components"

Gibbs Triangle

An Equilateral triangle on which the pure components are represented by each corner.



Concentration can be expressed as either "wt. %" or "at.% = molar %".

 $X_A + X_B + X_C = 1$

Used to determine the overall composition

Overall Composition



Overall Composition



21

<u>Isomorphous System</u>: A system (ternary in this case) that has only one solid phase. All components are totally soluble in the other components. The ternary system is therefore made up of three binaries that exhibit total solid solubility.

<u>The Liquidus surface</u>: A plot of the temperatures above which a homogeneous liquid forms for any given overall composition.

<u>The Solidus Surface</u>: A plot of the temperatures below which a (homogeneous) solid phase forms for any given overall composition.











26

Isothermal section \rightarrow F = C - P



Isothermal section



Ternary Isomorphous System Isothermal section $\rightarrow F = C - P$



- Fig. 1.41 (a) Free energy surface of a liquid and three solid phases of a ternary system.
- (b) A tangential plane construction to the free energy surfaces defined equilibrium between s and I in the ternary system
- (c) Isothermal section through a ternary phase diagram

Locate overall composition using Gibbs triangle













35









T= ternary eutectic temp.





TA: Melting Point Of Material A

T_B: Melting Point Of Material B

T_C: Melting Point Of Material C

TE1: Eutectic Temperature Of A-B

TE2: Eutectic Temperature Of B-C

TE3: Eutectic Temperature Of C-A



42













T= ternary eutectic temp.



49

(with Solid Solubility)



3) Solidification Sequence: liquidus surface





- * The horizontal lines are not tie lines. (no compositional information)
- * Information for equilibrium phases at different tempeatures 52

< Quaternary phase Diagrams >





* Incentive Homework 1

Please submit ternary phase diagram model which can clearly express 3D structure of ternary system by October 16 in Bldg. 33-313. You can submit the model individually or with a small group under 3 persons.

* Homework 1 : Exercises 1 (pages 61-63)

Good Luck!!

